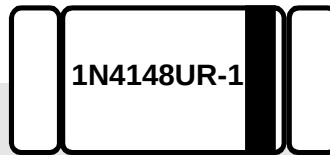


MINI-MELF-SMD



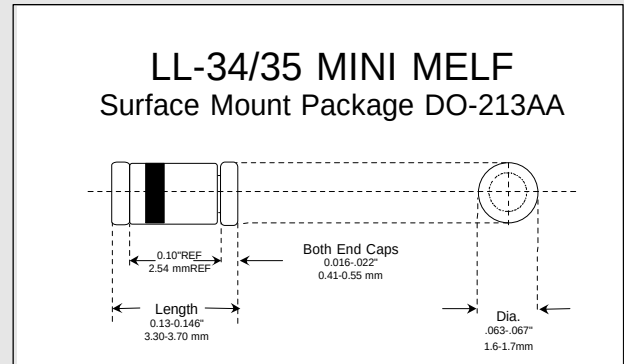
Silicon Diode Switching

Applications

Used in general purpose applications, where a low current controlled forward characteristic and fast switching speed are important.

Features

- Six sigma quality
- Metallurgically bonded
- BKC's Sigma Bond™ plating for problem free solderability
- Available in DO-35 package
- Approved to Mil-S-19500/116



Maximum Ratings	Symbol	Value	Unit
Peak Inverse Voltage	PIV	100 (Min.)	Volts
Average Rectified Current	I_{Avg}	200	mAmps
Continuous Forward Current	I_{Edc}	400	mAmps
Peak Surge Current ($t_{peak} = 1 \text{ sec.}$)	I_{peak}	0.5	Amp
Power Dissipation @ Endcap Temp. = 25 °C	P_{tot}	500	mWatts
Storage & Operating Temperature Range	$T_{St \& Op}$	-65 to +200	°C

Electrical Characteristics @ 25°C*	Symbol	Absolute Limits	Unit
Forward Voltage Drop @ $I_F = 10 \text{ mA}$	V_F	1.0	Volts
Reverse Leakage Current @ $V_R = 20 \text{ V}$	I_R	0.025	μA
Breakdown Voltage @ $I_R = 5 \text{ μA}$	PIV	75 (MIN)	Volts
Breakdown Voltage @ $I_R = 100\text{μA}$	PIV	100 (MIN)	Volts
Reverse Leakage Current @ $V_R = 20 \text{ V}$	I_R	0.025 (MAX)	μA
Reverse Leakage ($V_r = 20 \text{ V, } 150 \text{ °C}$)	I_R	50 (MAX)	μA
Capacitance @ $V_R = 0 \text{ V, } f = 1\text{mHz}$	C_T	4.0 (MAX)	pF
Reverse Recovery Time (note 1)	t_{rr}	4.0 (MAX)	nSecs

Note 1: $I_F = 10 \text{ mA}$, $R_L = 100 \text{ Ohms}$, $V_r = 6.0 \text{ Volts}$, $I_{rr} = 1.0 \text{ mA}$ *UNLESS OTHERWISE SPECIFIED



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